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APPLICANTS

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** CONTINUING DATA *****

This application is a CON of 10/293,154 11/13/2002 ABN ✓
 which is a CON of 09/484,473 01/18/2000 PAT 6,620,738
 which is a DIV of 09/116,725 07/16/1998 ABN

** FOREIGN APPLICATIONS *****

JAPAN 9-191179 07/16/1997 ✓

IF REQUIRED, FOREIGN FILING LICENSE GRANTED

** 01/14/2004

Foreign Priority claimed <input checked="" type="checkbox"/> yes <input type="checkbox"/> no	STATE OR COUNTRY JAPAN	SHEETS DRAWING 5	TOTAL CLAIMS 4	INDEPENDENT CLAIMS 1
35 USC 119 (a-d) conditions met <input checked="" type="checkbox"/> yes <input type="checkbox"/> no <input type="checkbox"/> Met after				
Verified and Acknowledged	Examiner's Signature <i>Quam</i>	Initials <i>OS</i>		

ADDRESS

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TITLE

Etchant and method for fabricating a semiconductor device using the same

FILING FEE	FEES: Authority has been given in Paper	<input type="checkbox"/> All Fees <input type="checkbox"/> 1.16 Fees (Filing) <input type="checkbox"/> 1.17 Fees (Processing Ext. of
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